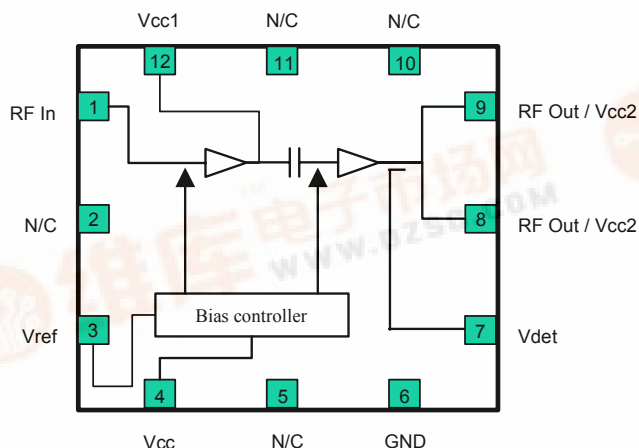




Product Description:

The TQP2420G is a high performance, high linearity, medium-power amplifier designed for 802.11b/g WLAN and other applications in the 2.4GHz ISM band. The device exhibits industry-leading power added efficiency under 802.11b and 802.11g modulated signals. The power amplifier is manufactured using TriQuint's InGaP HBT process and is packaged in an industry standard 3mm x 3mm VQFN-12 package.

Selected Electrical Specifications:

Parameter	min	typ	max	units
Frequency Range	2400	-	2500	MHz
Power Gain	28	29		dB
Linear Output Power (802.11g modulation)		19		dBm
Error Vector Magnitude (Pout = +19dBm, 54Mbps OFDM Signal)		2		%
Linear Output Power (guaranteed ACP under 802.11b modulation)	22	23		dBm
802.11b ACP; +22.0 dBm Output; 1 st Side Lobe		-35		dBc
802.11b ACP; +22.0 dBm Output; 2 nd Side Lobe		-56		dBc

Test Conditions: $T_a = 25^\circ\text{C}$; $V_{ref} = 2.95\text{V}$; $V_{cc} = V_{c1} = V_{c2} = 3.3\text{V}$

2.4GHz ISM Band InGaP HBT Power Amplifier

Features

- High Linearity, 2.4 GHz ISM Band PA for 802.11b/g WLAN Systems
- Integrated Output Power Detector
- Leadless 3.0 x 3.0 mm SMT Package
- Temperature Compensated Bias Network with Bias Shutdown Mode
- EVM < 2% @ +19dBm Linear Output Power 802.11g modulation
- +23 dBm Linear Output Power 802.11b modulation

Applications

- 802.11b/g WLAN
- 2.4GHz ISM Band Applications
- Cordless Phones
- Broadband Systems

TQP2420G

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Absolute Maximum Ratings

Parameter	Symbol	Value		Unit
		min	max	
Power Supply Voltage (no RF applied)	Vc1, Vc2, Vcc		6.0	V
Power Supply Voltage (RF applied)	Vc1, Vc2, Vcc		5.0	V
Reference Voltage	Vref		3.0	V
Power Dissipation	Pdiss			W
Case Temperature, Survival	Tc	-40	100	°C
Storage Temperature	T _a	-40	150	°C
Operating Temperature Range	Toper	-40	85	°C
RF Input Power	Pin		+5dBm	dBm

General Electrical Characteristics^{1,2}

Parameter	min	typ	max	Unit
Frequency Range	2400	-	2500	Mhz
Output Power @ 1dB Gain Compression		24		dBm
Power Gain	28	29		dB
Linear Output Power (802.11g modulation)		19		dBm
Error Vector Magnitude (Pout=+19dBm, 54Mbps OFDM Signal)		2		%
Linear Output Power (guaranteed ACP under 802.11b modulation)	22	23		dBm
Gain Variation vs. Frequency		0.4		dB p-p
Power Added Efficiency @ Linear Output Power = +22dBm, with 802.11b CCK modulation		35		%
802.11b Adjacent Channel Power @ +22.0 dBm Output power – 1 st Side Lobe		-35		dBc
802.11b Adjacent Channel Power @ +22.0 dBm Output power – 2 nd Side Lobe		-56		dBc
Input VSWR with external matching)			2:1	

¹Test Conditions: T_a=25°C, Vref=2.95V, Vcc=Vc1=Vc2=3.3V

²AC performance is guaranteed at 25 Deg-C, Vcc=Vc1=Vc2=3.3V, Vref=2.95V

DC Electrical Performance* At Vref=2.95V typical

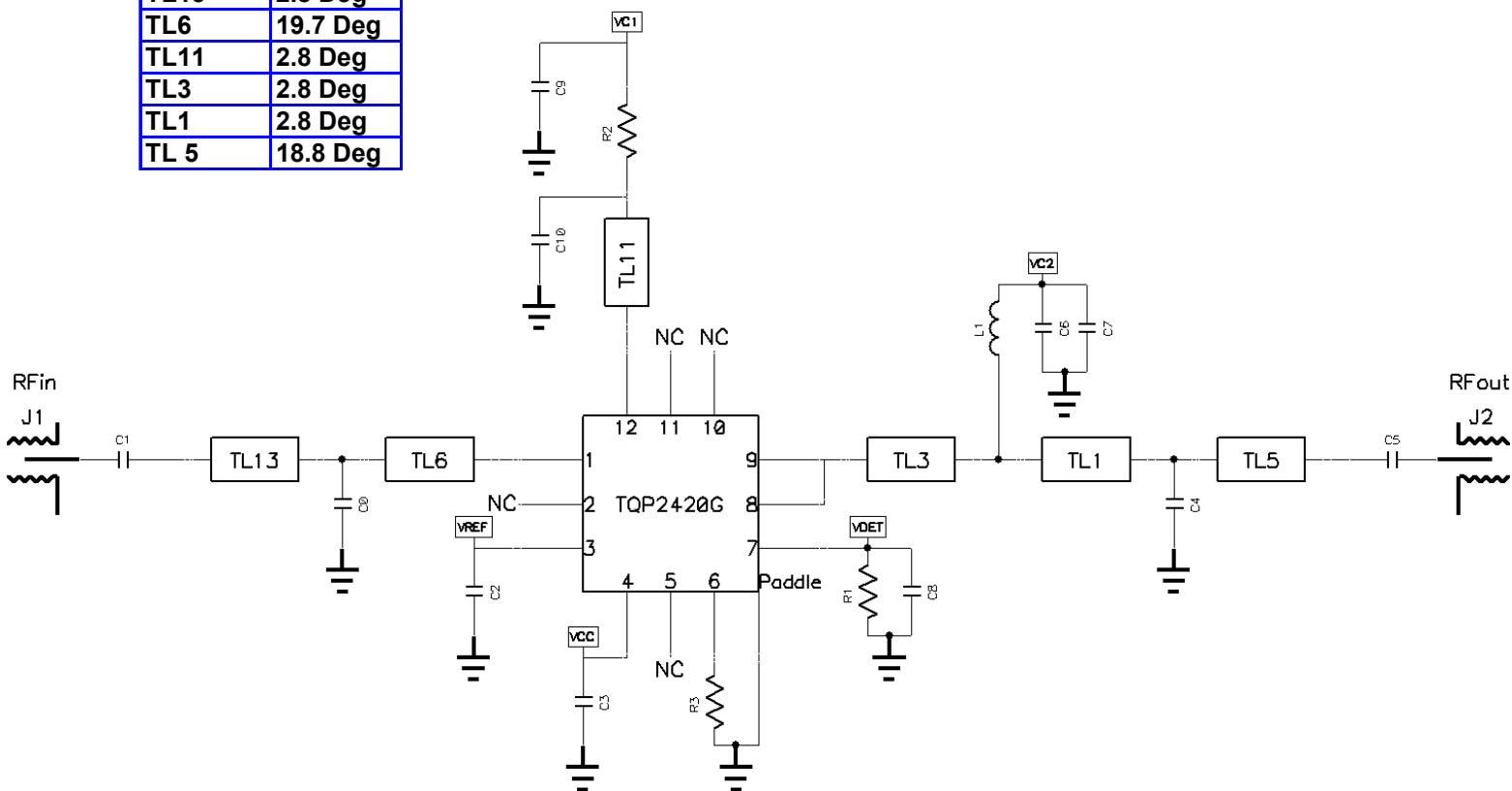
Parameter,	min	typ	max	Unit
Operating Voltage Supply Range	3.0	3.3	3.6	V
Supply Current: $T_a = 25^\circ\text{C}$, $V_{cc}=V_{ref}=2.95$ $V_{c1}=V_{c2}= 3.3\text{V}$ Linear Output Power = 19dBm, with 802.11g 54Mbps modulation		130		mA
Supply Current: $T_a = 25^\circ\text{C}$, $V_{cc}=V_{ref}=2.95$ $V_{c1}=V_{c2}= 3.3\text{V}$ Linear Output Power = 22dBm, with 802.11b CCK modulation		180		mA
Vref	2.85	2.95	3.0	
I_{vref}		2		mA
Shutdown Mode Current		<1		uA
Quiescent current*		60		mA

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Schematic

TL13	2.8 Deg
TL6	19.7 Deg
TL11	2.8 Deg
TL3	2.8 Deg
TL1	2.8 Deg
TL 5	18.8 Deg



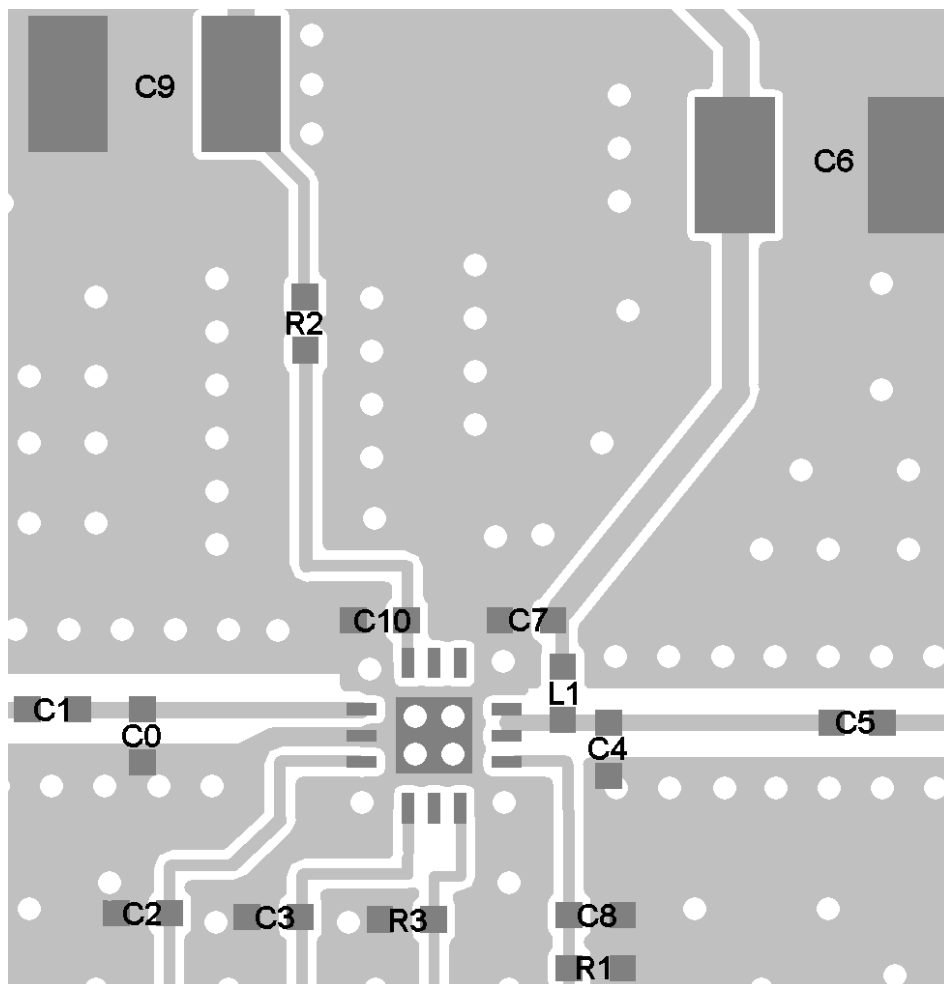
Pin Assignments

Pin	Symbol	Description
1	RFin	RF Input
2	N/C	
3	Vref	Bias Reference voltage
4	Vcc*	Bias circuit supply voltage,
5	N/C	
6	GND	Ground
7	Vdet	Power detector output voltage
8	RFout, Vcc2	RF Output and 2 nd stage collector supply voltage
9	RFout, Vcc2	RF Output and 2 nd stage collector supply voltage
10	N/C	
11	N/C	
12	Vcc1	1 st stage collector supply voltage
	GND	Backside Paddle

*Vcc may be connected directly to Vc1 or Vc2 on DC side of RF Choke

TQP2420G Datasheet

Evaluation Board-WLAN PA; 242x Evaluation board



Layer/Descriptions
 Dielectric: FR4: Er=4.6
 Top: 1 oz. Plated Copper
 Dielectric 1 : 6 mils
 Mid 1: 1 oz. Copper
 Dielectric 2: 28 mils
 Mid 2: 1 oz. Copper
 Dielectric 3: 6 mils
 Bottom: 1 oz. Plated Copper

Bill of Materials

		Evaluation Board		242X				
		Integrated Circuit ID		TQP2420				
Part #	Quantity	Component ID	Size	Value	Units	Manufacturer	P/N	Comments
1	1	C0	0402	1.2	pF	Skywell	042CG1R2C500BA	
2	1	C5	0402	1.5	pF	Skywell	042CG1R5C500BA	
3	1	C1	0402	2.2	pF	Rohm	MCH155A2R2CK	
4	3	C2,C3,C7	0402	0.033	uF	Murata	GRP155R71A333KA01B	
5	1	C4	0402	2.7	pF	Rohm	MCH155A2R7CK	
6	2	C6,C9	.130x.070	10	uF	Murata	GJ232RF51E106ZD01K	
7	1	C10	0402	22	pF	Murata	GRP1555C1H220JZ01B	
8	1	R1	0402	10000	ohms	Rhom	MCR01J133	
9	1	R2	0402	0	ohms	Rhom		
10	1	R3	0402	0	ohms	Rohm		
11	1	L2	0402	6.8	nH	Toko	LL1005-FH6N8J	
12	1	C8	0402	10	pF	Murata	GRP1555C1H100JZ01B	
13	1	Q1	MLF		N/A	Triquint	TQP2420G	
14	2	J1,J2				Johnson	142-0711-881	
15	2	J3,J4						DC Connector
16	1	PCB					242X	Printed circuit board

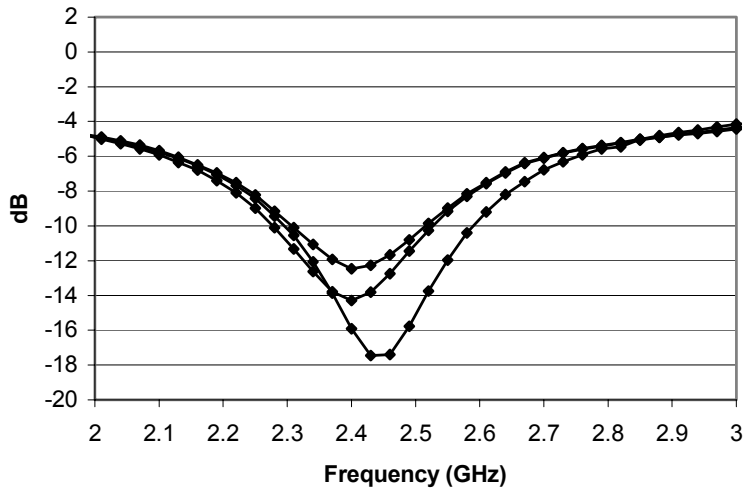
TQP2420G

Datasheet

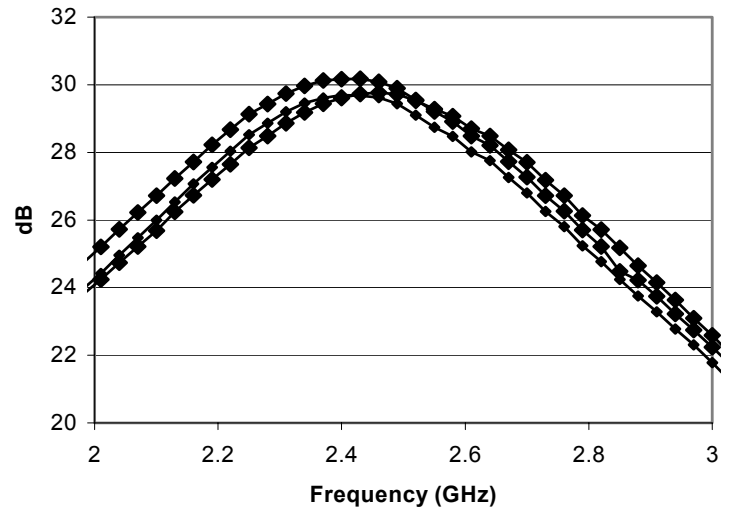
TQP2420G measured Small Signal performance; in TriQuint WLAN242X Evaluation Board

Measurement Conditions: $T_a = 25^\circ\text{C}$, $V_{\text{ref}} = 2.95$ V, $V_{\text{cc}} = V_{\text{c1}} = V_{\text{c2}} = 3.3$ V, Sample size 9 Units

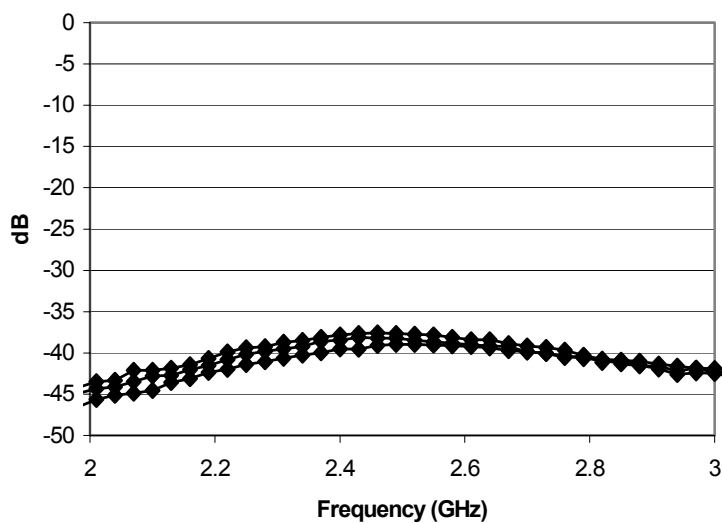
S11
TQP2420G
3 samples



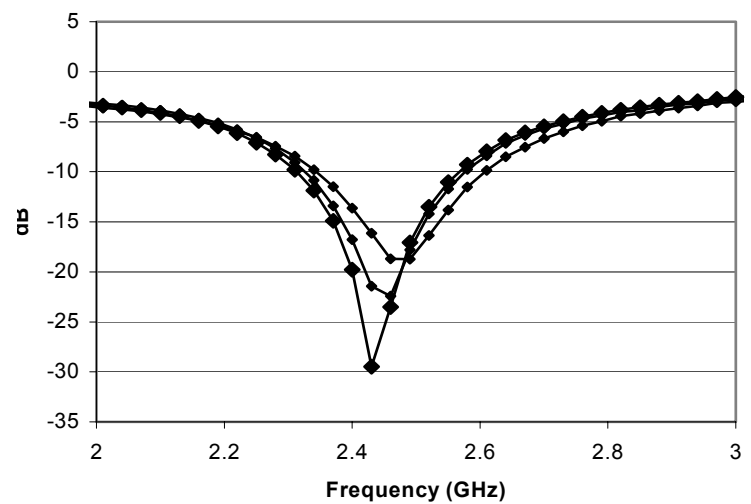
S21
TQP2420G
3 samples



S12
TQP2420G
3 samples



S22
TQP2420G
3 samples



TQP2420G measured 802.11g performance; in TriQuint WLAN242X Evaluation Board- Continued

Measurement conditions: $T_a = 25^{\circ}\text{C}$, $V_{\text{ref}}=2.9$, $V_{\text{cc}}=V_{\text{c1}}=V_{\text{c2}}= 3.3\text{V}$, $f=2450\text{MHz}$

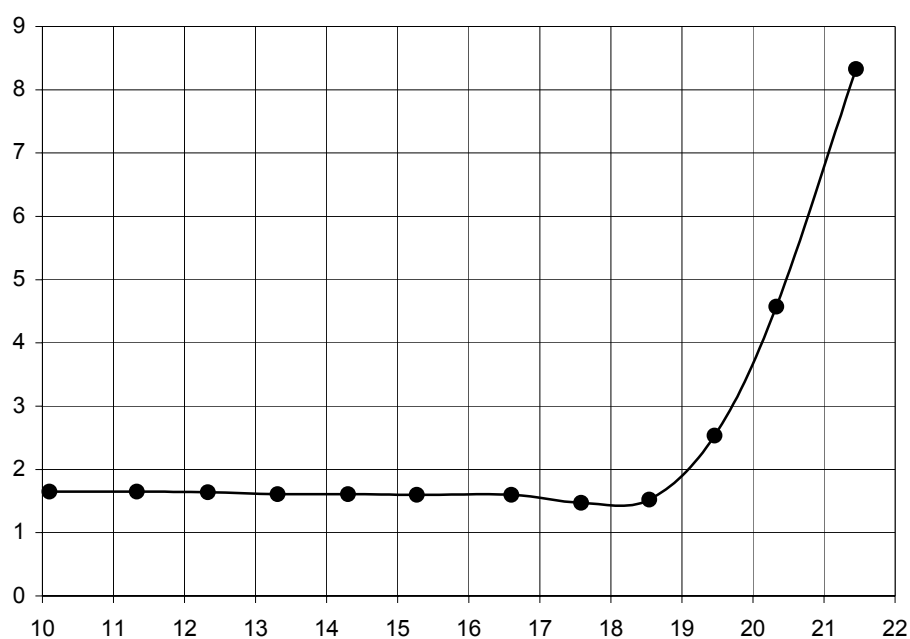
TQP2420G

Measured EVM vs Output power

802.11g 54mbps

$f=2.45\text{ GHz}$

S/N 55



$I_{\text{tot}} = 132\text{mA}$ @ $P_{\text{out}} = +19\text{dBm}$, 54Mbps OFDM Signal

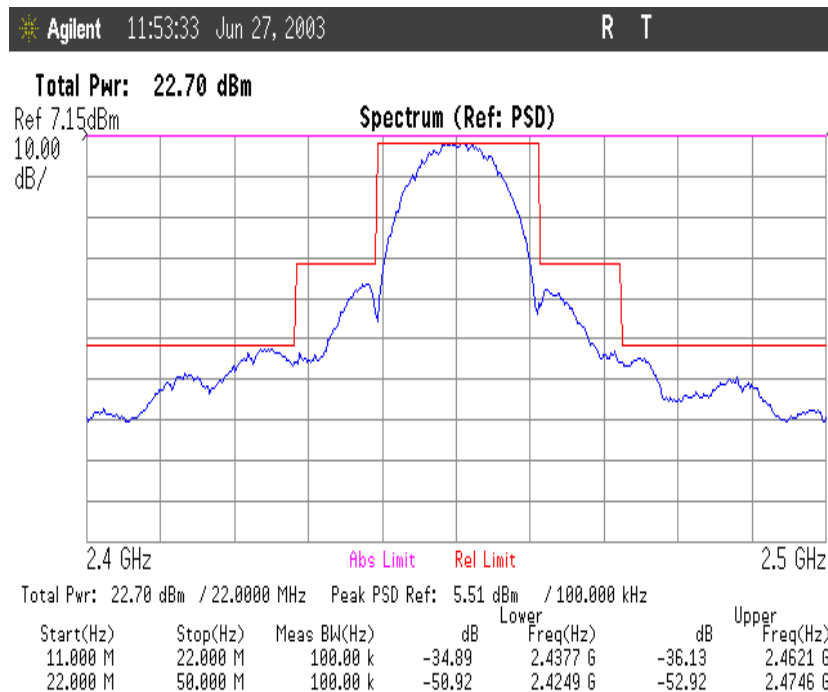
TQP2420G

Datasheet

TQP2420G measured 802.11b performance; in TriQuint WLAN242X Evaluation Board- Continued

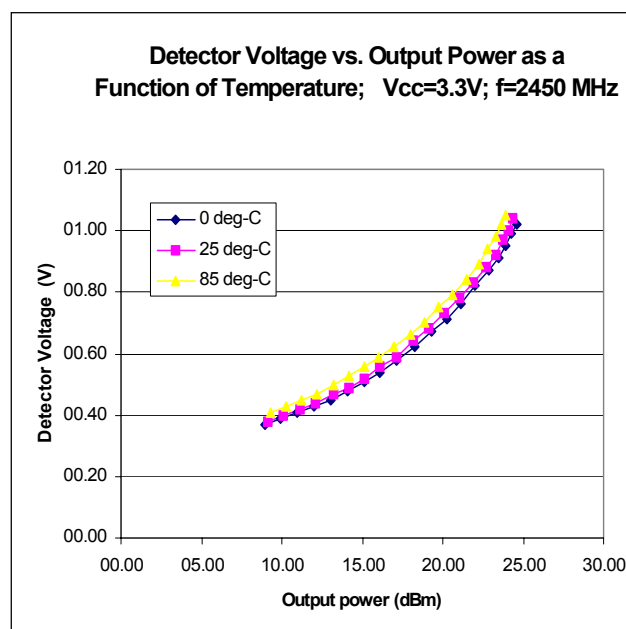
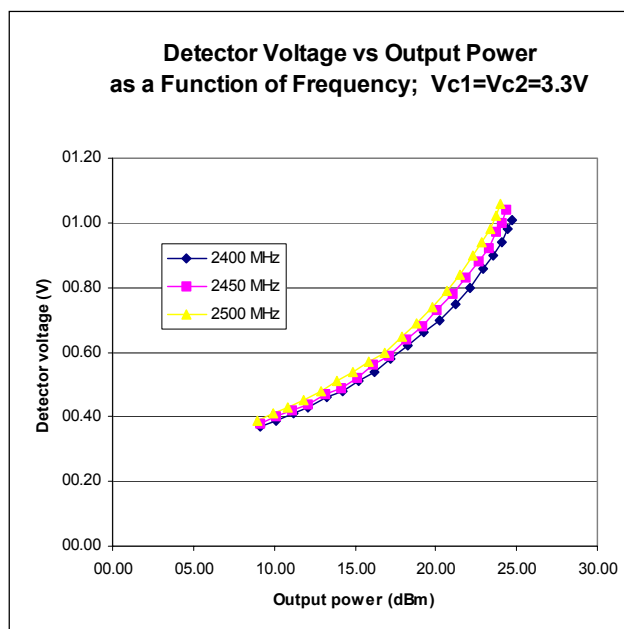
Measurement conditions: $T_a = 25^{\circ}\text{C}$, $V_{\text{ref}}=2.9$, $V_{\text{cc}}=V_{\text{c1}}=V_{\text{c2}}= 3.3\text{V}$, $f=2450\text{MHz}$

Transmit Spectral Mask-Typical performance



TQP2420G measured performance; in TriQuint WLAN242X Evaluation Board- Continued

Measurement conditions $T_a = 25^\circ\text{C}$, $V_{\text{ref}}=2.9$, $V_{\text{cc}}=V_{\text{c1}}=V_{\text{c2}}= 3.3\text{V}$



TQP2420G
Datasheet

Application Data

External matching

•The 50 Ohm match of the input and output ports of the TQP2420G is completed by the addition of a small number of external components. The optimum impedance presented to the respective ports is described in the Smith Chart plot at the right.

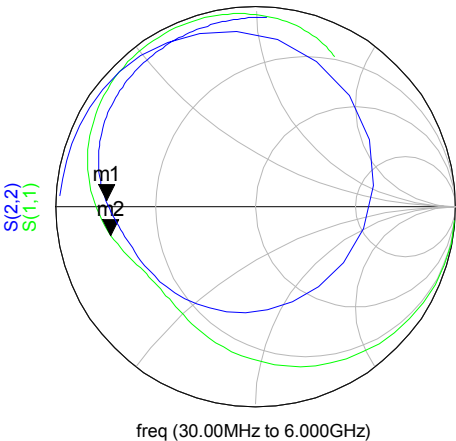
•The impedance shown can be achieved by a number of topologies. The preferred topology selected for Triquint 242x evaluation board is shown in the schematic.

Source

Load

m1
freq=2.480GHz
S(2,2)=0.750 / 177.603
impedance = Z0 * (0.143 + j0.020)

m2
freq=2.480GHz
S(1,1)=0.739 / -168.987
impedance = Z0 * (0.151 - j0.094)



Source

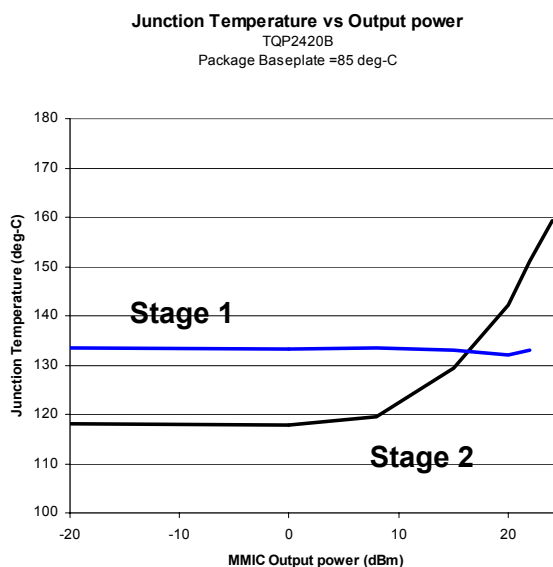
Load

freq	S(1,1)
30.00MHz	0.999 / -3.957
230.0MHz	0.967 / -29.806
430.0MHz	0.903 / -53.507
630.0MHz	0.829 / -74.166
830.0MHz	0.761 / -91.703
1.030GHz	0.706 / -106.400
1.230GHz	0.666 / -118.632
1.430GHz	0.640 / -128.809
1.630GHz	0.630 / -137.406
1.830GHz	0.635 / -144.982
2.030GHz	0.654 / -152.132
2.230GHz	0.687 / -159.368
2.430GHz	0.728 / -167.002
2.630GHz	0.773 / -175.121
2.830GHz	0.819 / 176.361
3.030GHz	0.860 / 167.614
3.230GHz	0.896 / 158.820
3.430GHz	0.925 / 150.128
3.630GHz	0.948 / 141.643
3.830GHz	0.964 / 133.423
4.030GHz	0.975 / 125.491
4.230GHz	0.981 / 117.850
4.430GHz	0.982 / 110.485
4.630GHz	0.980 / 103.380
4.830GHz	0.973 / 96.518
5.030GHz	0.963 / 89.892
5.230GHz	0.948 / 83.512
5.430GHz	0.929 / 77.411
5.630GHz	0.905 / 71.655
5.830GHz	0.877 / 66.344
6.000GHz	0.852 / 62.271

freq	S(2,2)
30.00MHz	0.981 / 176.647
230.0MHz	0.972 / 155.219
430.0MHz	0.950 / 127.187
630.0MHz	0.844 / 82.634
830.0MHz	0.601 / 10.089
1.030GHz	0.509 / -68.802
1.230GHz	0.556 / -114.349
1.430GHz	0.598 / -138.063
1.630GHz	0.627 / -152.220
1.830GHz	0.651 / -161.741
2.030GHz	0.678 / -168.936
2.230GHz	0.708 / -175.101
2.430GHz	0.741 / 179.055
2.630GHz	0.774 / 173.238
2.830GHz	0.804 / 167.397
3.030GHz	0.830 / 161.580
3.230GHz	0.852 / 155.844
3.430GHz	0.870 / 150.230
3.630GHz	0.884 / 144.755
3.830GHz	0.895 / 139.422
4.030GHz	0.905 / 134.221
4.230GHz	0.912 / 129.140
4.430GHz	0.919 / 124.164
4.630GHz	0.924 / 119.274
4.830GHz	0.929 / 114.457
5.030GHz	0.933 / 109.694
5.230GHz	0.937 / 104.969
5.430GHz	0.941 / 100.267
5.630GHz	0.944 / 95.573
5.830GHz	0.948 / 90.874
6.000GHz	0.951 / 86.866

Device Junction Temperature

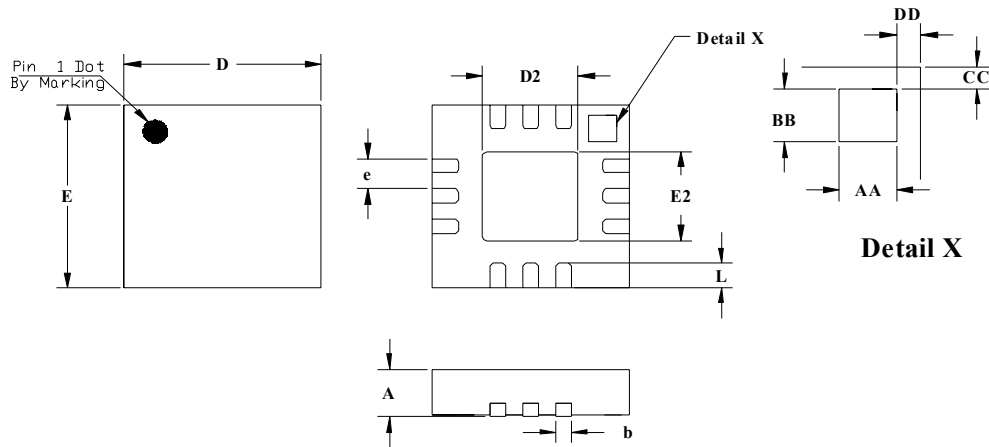
•The plot is an estimate of the first and second stage transistor temperatures for an amplifier biased at a collector voltage of 3.3V and $V_{ref} = 2.95V$. The paddle temperature is +85 deg-C. The actual temperature will vary dependent on the method used to attach the package to the final assembly board.



TQP2420G

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Package Outline



JEDEC DESIGNATION	DESCRIPTION	METRIC	ENGLISH	NOTE
A	OVERALL HEIGHT	0.90 +/- .10 mm	.035 +/- .004 in	1
b	TERMINAL WIDTH	0.23 +/- .07 mm	.009 +/- .003 in	1
D	PACKAGE LENGTH	3.00 mm BSC	.118 in	1
D2	EXPOSED PAD LENGTH	1.45 +/- .10 mm	.057 +/- .004 in	1
e	TERMINAL PITCH	0.50 mm BSC	.020 in	1
E	PACKAGE WIDTH	3.00 mm BSC	.118 in	1
E2	EXPOSED PAD WIDTH	1.45 +/- .10 mm	.057 +/- .004 in	1
L	TERMINAL LENGTH	0.40 +/- .10 mm	.016 +/- .004 in	1
AA	PIN 1 ID LENGTH	0.43 mm BSC	.017 in	1
BB	PIN 1 ID WIDTH	0.43 mm BSC	.017 in	1
CC	PIN 1 ID TO EDGE	0.18 mm BSC	.007 in	1
DD	PIN 1 ID TO EDGE	0.18 mm BSC	.007 in	1

Notes:
 1. PRIMARY DIMENSIONS ARE IN METRIC MILLIMETERS. THE ENGLISH EQUIVALENTS ARE CALCULATED AND SUBJECT TO ROUNDING ERROR.

Package Marking

Pin 1



Line 1: 2420
Line 2: XXXX TriQuint Assembly Lot Number
Line 3: Manufacturing year and work week

Ordering Information:

Type	Marking	Package
TQP2420G	2420	VQFN-12

Caution: Electrostatic discharge sensitive. Observe handling Precautions!

Additional Information

For latest specifications, additional product information, worldwide sales and distribution locations, and information about TriQuint:

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Fax: (503) 615-8902

For technical questions and additional information on specific applications:

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